



UT8205A

Power MOSFET

N-CHANNEL ENHANCEMENT MODE

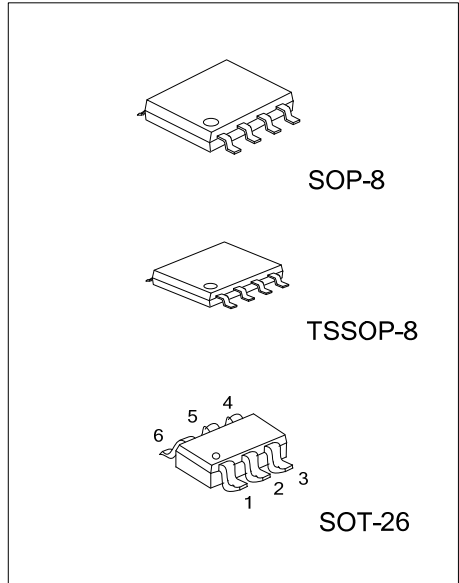
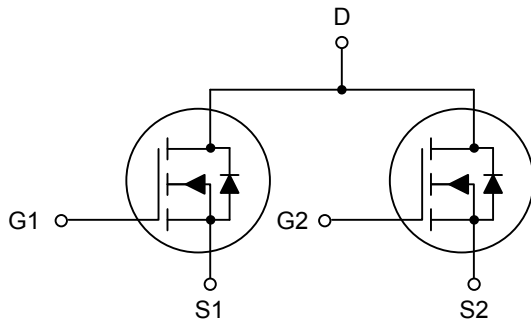
DESCRIPTION

The **UT8205A** uses advanced technology to provide fast switching, low on-resistance and cost-effectiveness. This device is suitable for all commercial-industrial surface mount applications.

FEATURES

- * $R_{DS(ON)} \leq 28 \text{ m}\Omega$ @ $V_{GS}=4.5\text{V}$, $I_D=6.0\text{A}$
- * Ultra low gate charge (typical 23 nC)
- * Low reverse transfer Capacitance (C_{RSS} = typical 150 pF)
- * Fast switching capability
- * Avalanche energy Specified
- * Improved dv/dt capability, high ruggedness

SYMBOL



ORDERING INFORMATION

Ordering Number	Package	Pin Assignment								Packing
		1	2	3	4	5	6	7	8	
UT8205AG-AG6-R	SOT-26	S1	D	S2	G2	D	G1	-	-	Tape Reel
UT8205AG-S08-R	SOP-8	D	S1	S1	G1	G2	S2	S2	D	Tape Reel
UT8205AG-P08-R	TSSOP-8	D	S1	S1	G1	G2	S2	S2	D	Tape Reel

Note: Pin Assignment: S: Source G: Gate D: Drain

UT8205AG-AG6-R		(1) Packing Type	(1) R: Tape Reel
		(2) Package Type	(2) AG6: SOT-26, P08: TSSOP-8, S08: SOP-8
		(3) Green Package	(3) G: Halogen Free and Lead Free

MARKING

SOP-8	TSSOP-8	SOT-26

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DS}	20	V
Gate-Source Voltage		V_{GS}	± 12	V
Drain Current (Note 2)	Continuous	I_D	6	A
	Pulsed	I_{DM}	20	A
Power Dissipation ($T_a=25^\circ\text{C}$) (Note 3)	SOT-26	P_D	1.14	W
	SOP-8/TSSOP-8		1	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse Test : Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$

3. Pulse width limited by $T_{J(MAX)}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient (Note)	SOT-26	θ_{JA}	110	$^\circ\text{C/W}$
	SOP-8		78	$^\circ\text{C/W}$
	TSSOP-8		125	$^\circ\text{C/W}$

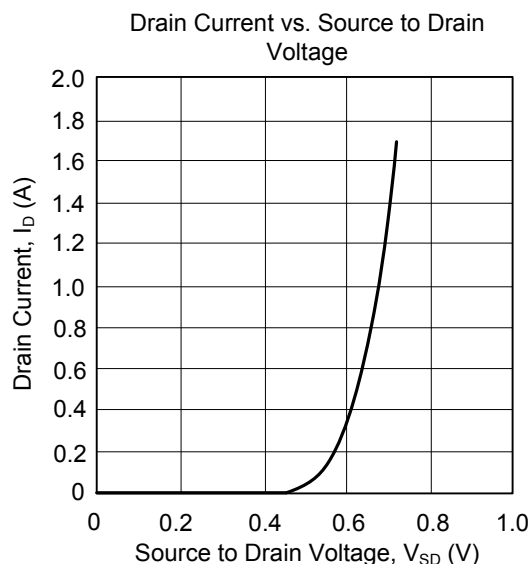
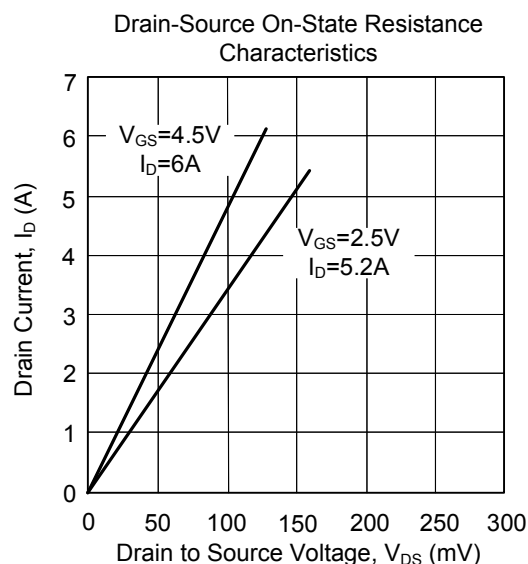
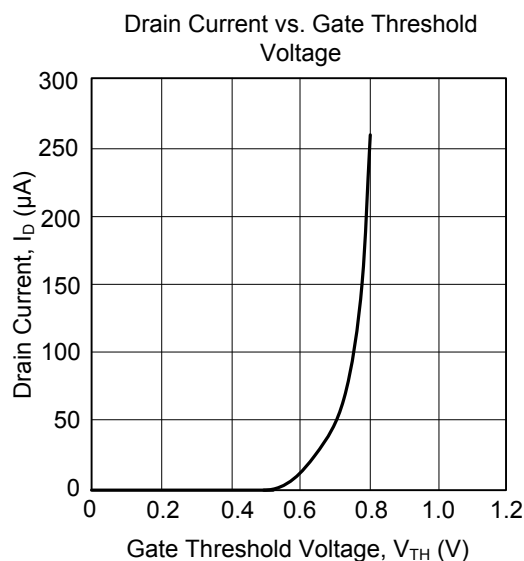
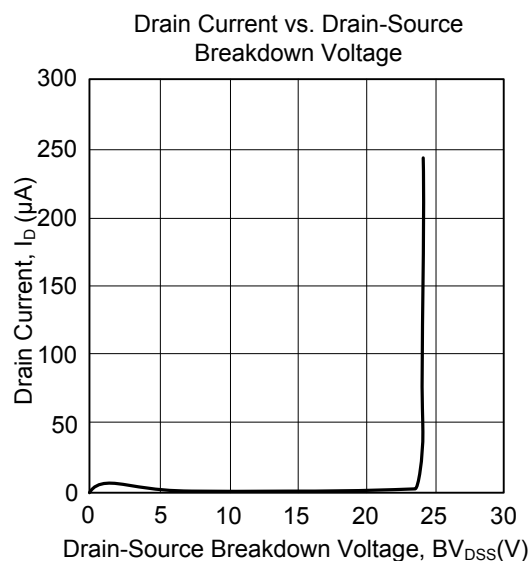
Note: Pulse Test : Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$

■ ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	20			V
Breakdown Voltage Temperature Coefficient	$\frac{\Delta BV_{DSS}}{\Delta T_J}$	I _D =1mA, Reference to 25°C		0.03		V/°C
Drain-Source Leakage Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V,			1	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	0.5		1.5	V
Drain-Source On-State Resistance (Note)	R _{DS(ON)}	V _{GS} =4.5V, I _D =6.0A			28	mΩ
		V _{GS} =2.5V, I _D =5.2A			38	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{DS} =20V, V _{GS} =0V, f=1.0MHz		1035		pF
Output Capacitance	C _{OSS}			320		pF
Reverse Transfer Capacitance	C _{RSS}			150		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time (Note)	t _{D(ON)}	V _{GS} =5V, V _{DS} =10V, R _D =10Ω, R _G =6Ω, I _D =1A		30		ns
Turn-ON Rise Time	t _R			70		ns
Turn-OFF Delay Time	t _{D(OFF)}			40		ns
Turn-OFF Fall-Time	t _F			65		ns
Total Gate Charge(Note)	Q _G	V _{DS} =20V, V _{GS} =5V, I _D =6.0A		23		nC
Gate Source Charge	Q _{GS}			4.5		nC
Gate Drain Charge	Q _{GD}			7		nC
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Drain-Source Diode Forward Voltage (Note)	V _{SD}	I _S =1.7A, V _{GS} =0V			1.2	V
Diode Continuous Forward Current	I _S	V _D =V _G , V _S =1.3V			1.54	A

Note: Surface mounted on 1 in² copper pad of FR4 board; 208 $^\circ\text{C/W}$ when mounted on min.

■ TYPICAL CHARACTERISTICS



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.